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Kind regards,

Team Nexperia

# 74LVC2G53

## 2-channel analog multiplexer/demultiplexer

Rev. 10 — 15 December 2016

Product data sheet

### 1. General description

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The 74LVC2G53 is a low-power, low-voltage, high-speed, Si-gate CMOS device.

The 74LVC2G53 provides one analog multiplexer/demultiplexer with a digital select input (S), two independent inputs/outputs (Y0 and Y1), a common input/output (Z) and an active LOW enable input ( $\overline{E}$ ). When pin  $\overline{E}$  is HIGH, the switch is turned off.

Schmitt trigger action at the select and enable inputs makes the circuit tolerant of slower input rise and fall times across the entire  $V_{CC}$  range from 1.65 V to 5.5 V.

### 2. Features and benefits

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- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
  - ◆ 7.5  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - ◆ 6.5  $\Omega$  (typical) at  $V_{CC} = 3.3$  V
  - ◆ 6  $\Omega$  (typical) at  $V_{CC} = 5$  V
- Switch current capability of 32 mA
- High noise immunity
- CMOS low-power consumption
- TTL interface compatibility at 3.3 V
- Latch-up performance meets requirements of JESD 78 Class I
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Control inputs accept voltages up to 5 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and from  $-40$  °C to  $+125$  °C



### 3. Ordering information

Table 1. Ordering information

| Type number | Package           |        |                                                                                             |          |
|-------------|-------------------|--------|---------------------------------------------------------------------------------------------|----------|
|             | Temperature range | Name   | Description                                                                                 | Version  |
| 74LVC2G53DP | –40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm     | SOT505-2 |
| 74LVC2G53DC | –40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                  | SOT765-1 |
| 74LVC2G53GT | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 |
| 74LVC2G53GF | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm         | SOT1089  |
| 74LVC2G53GD | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm    | SOT996-2 |
| 74LVC2G53GM | –40 °C to +125 °C | XQFN8  | plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm   | SOT902-2 |
| 74LVC2G53GN | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm       | SOT1116  |
| 74LVC2G53GS | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm      | SOT1203  |

### 4. Marking

Table 2. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 74LVC2G53DC | V53                         |
| 74LVC2G53DP | V53                         |
| 74LVC2G53GT | V53                         |
| 74LVC2G53GF | V3                          |
| 74LVC2G53GD | V53                         |
| 74LVC2G53GM | V53                         |
| 74LVC2G53GN | V3                          |
| 74LVC2G53GS | V3                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 5. Functional diagram

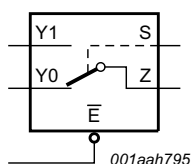


Fig 1. Logic symbol

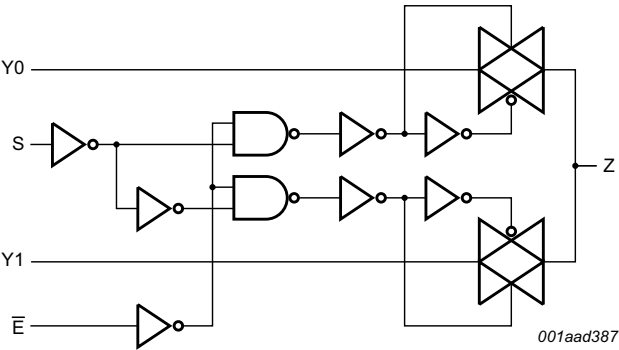


Fig 2. Logic diagram

6. Pinning information

6.1 Pinning

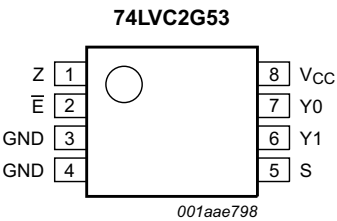


Fig 3. Pin configuration SOT505-2 and SOT765-1

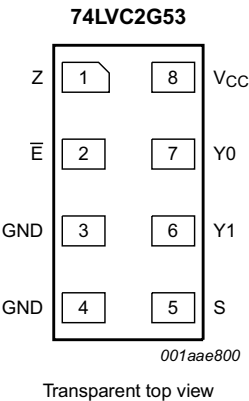
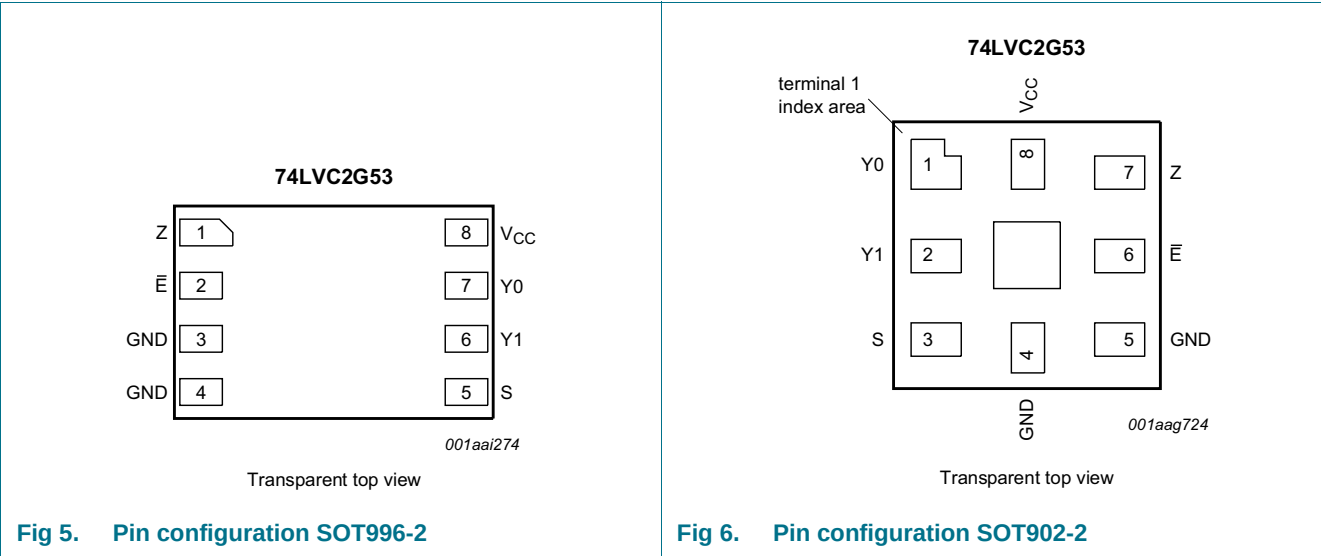


Fig 4. Pin configuration SOT833-1, SOT1089, SOT1116 and SOT1203



6.2 Pin description

Table 3. Pin description

| Symbol          | Pin                                                                  |          | Description                 |
|-----------------|----------------------------------------------------------------------|----------|-----------------------------|
|                 | SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203 | SOT902-2 |                             |
| Z               | 1                                                                    | 7        | common output or input      |
| $\overline{E}$  | 2                                                                    | 6        | enable input (active LOW)   |
| GND             | 3                                                                    | 5        | ground (0 V)                |
| GND             | 4                                                                    | 4        | ground (0 V)                |
| S               | 5                                                                    | 3        | select input                |
| Y1              | 6                                                                    | 2        | independent input or output |
| Y0              | 7                                                                    | 1        | independent input or output |
| V <sub>CC</sub> | 8                                                                    | 8        | supply voltage              |

7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input |                | Channel on         |
|-------|----------------|--------------------|
| S     | $\overline{E}$ |                    |
| L     | L              | Y0 to Z or Z to Y0 |
| H     | L              | Y1 to Z or Z to Y1 |
| X     | H              | Z (switch off)     |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                                                   | Min  | Max            | Unit |
|-----------|-------------------------|--------------------------------------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage          |                                                              | -0.5 | +6.5           | V    |
| $V_I$     | input voltage           | [1]                                                          | -0.5 | +6.5           | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$       | -50  | -              | mA   |
| $I_{SK}$  | switch clamping current | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$       | -    | $\pm 50$       | mA   |
| $V_{SW}$  | switch voltage          | enable and disable mode [2]                                  | -0.5 | $V_{CC} + 0.5$ | V    |
| $I_{SW}$  | switch current          | $V_{SW} > -0.5\text{ V}$ or $V_{SW} < V_{CC} + 0.5\text{ V}$ | -    | $\pm 50$       | mA   |
| $I_{CC}$  | supply current          |                                                              | -    | 100            | mA   |
| $I_{GND}$ | ground current          |                                                              | -100 | -              | mA   |
| $T_{stg}$ | storage temperature     |                                                              | -65  | +150           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$ [3]            | -    | 250            | mW   |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] For TSSOP8 packages: above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K.

For VSSOP8 packages: above 110 °C the value of  $P_{tot}$  derates linearly with 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 6. Operating conditions**

| Symbol              | Parameter                           | Conditions                                     | Min  | Max      | Unit |
|---------------------|-------------------------------------|------------------------------------------------|------|----------|------|
| $V_{CC}$            | supply voltage                      |                                                | 1.65 | 5.5      | V    |
| $V_I$               | input voltage                       |                                                | 0    | 5.5      | V    |
| $V_{SW}$            | switch voltage                      | enable and disable mode [1]                    | 0    | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                                                | -40  | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65\text{ V}$ to $2.7\text{ V}$ [2] | -    | 20       | ns/V |
|                     |                                     | $V_{CC} = 2.7\text{ V}$ to $5.5\text{ V}$ [2]  | -    | 10       | ns/V |

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

## 10. Static characteristics

**Table 7. Static characteristics**

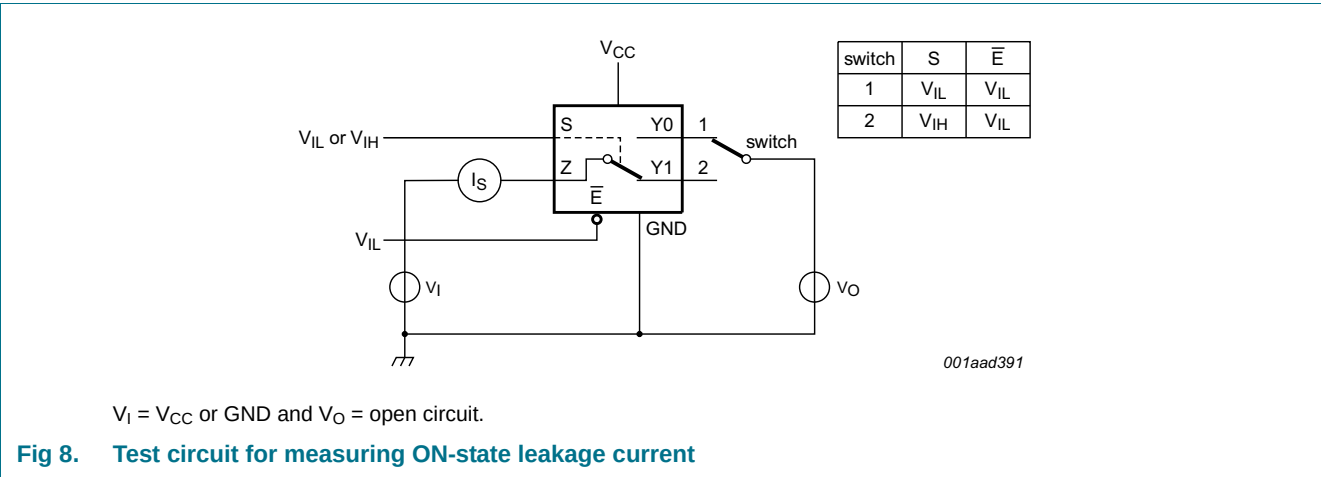
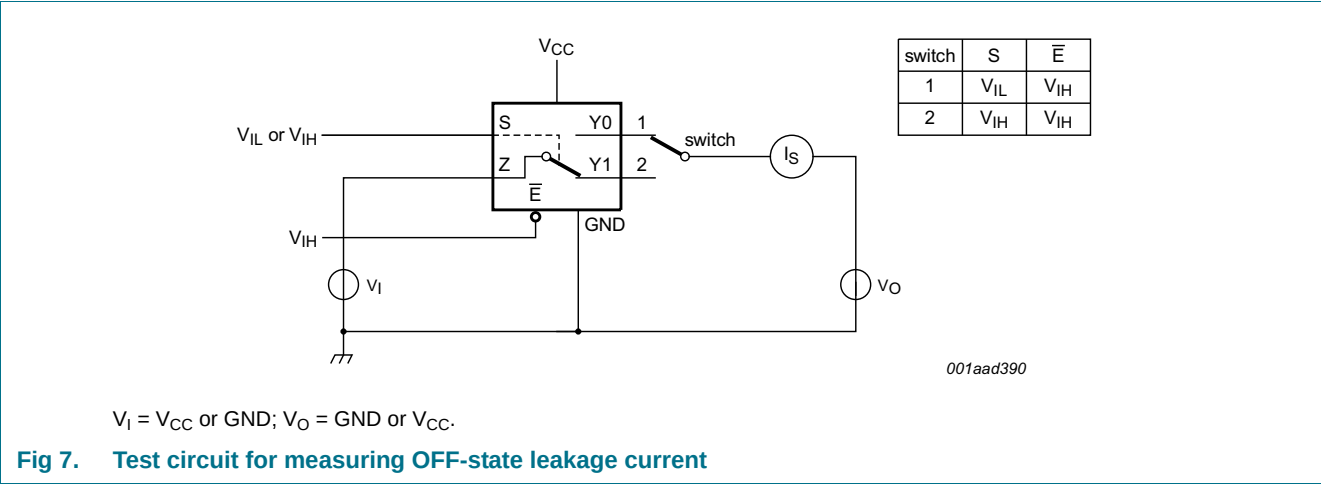
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol              | Parameter                 | Conditions                                                                                                                                      | T <sub>amb</sub> = –40 °C to +85 °C |                    |                        | T <sub>amb</sub> = –40 °C to +125 °C |                        | Unit |
|---------------------|---------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------|--------------------|------------------------|--------------------------------------|------------------------|------|
|                     |                           |                                                                                                                                                 | Min                                 | Typ <sup>[1]</sup> | Max                    | Min                                  | Max                    |      |
| V <sub>IH</sub>     | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                                                              | 0.65 × V <sub>CC</sub>              | -                  | -                      | 0.65 × V <sub>CC</sub>               | -                      | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                | 1.7                                 | -                  | -                      | 1.7                                  | -                      | V    |
|                     |                           | V <sub>CC</sub> = 3 V to 3.6 V                                                                                                                  | 2.0                                 | -                  | -                      | 2.0                                  | -                      | V    |
|                     |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                | 0.7 × V <sub>CC</sub>               | -                  | -                      | 0.7 × V <sub>CC</sub>                | -                      | V    |
| V <sub>IL</sub>     | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                                                              | -                                   | -                  | 0.35 × V <sub>CC</sub> | -                                    | 0.35 × V <sub>CC</sub> | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                | -                                   | -                  | 0.7                    | -                                    | 0.7                    | V    |
|                     |                           | V <sub>CC</sub> = 3 V to 3.6 V                                                                                                                  | -                                   | -                  | 0.8                    | -                                    | 0.8                    | V    |
|                     |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                | -                                   | -                  | 0.3 × V <sub>CC</sub>  | -                                    | 0.3 × V <sub>CC</sub>  | V    |
| I <sub>I</sub>      | input leakage current     | pin S and pin $\bar{E}$ ;<br>V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V                                                   | -                                   | ±0.1               | ±1                     | -                                    | ±1                     | μA   |
| I <sub>S(OFF)</sub> | OFF-state leakage current | V <sub>CC</sub> = 5.5 V;<br>see <a href="#">Figure 7</a>                                                                                        | -                                   | ±0.1               | ±0.2                   | -                                    | ±0.5                   | μA   |
| I <sub>S(ON)</sub>  | ON-state leakage current  | V <sub>CC</sub> = 5.5 V;<br>see <a href="#">Figure 8</a>                                                                                        | -                                   | ±0.1               | ±1                     | -                                    | ±2                     | μA   |
| I <sub>CC</sub>     | supply current            | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>SW</sub> = GND or V <sub>CC</sub> ;<br>V <sub>CC</sub> = 1.65 V to 5.5 V                               | -                                   | 0.1                | 4                      | -                                    | 4                      | μA   |
| ΔI <sub>CC</sub>    | additional supply current | pin S and pin $\bar{E}$ ;<br>V <sub>I</sub> = V <sub>CC</sub> – 0.6 V;<br>V <sub>SW</sub> = GND or V <sub>CC</sub> ;<br>V <sub>CC</sub> = 5.5 V | -                                   | 5                  | 500                    | -                                    | 500                    | μA   |
| C <sub>I</sub>      | input capacitance         |                                                                                                                                                 | -                                   | 2.5                | -                      | -                                    | -                      | pF   |
| C <sub>S(OFF)</sub> | OFF-state capacitance     |                                                                                                                                                 | -                                   | 6.0                | -                      | -                                    | -                      | pF   |
| C <sub>S(ON)</sub>  | ON-state capacitance      |                                                                                                                                                 | -                                   | 18                 | -                      | -                                    | -                      | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C.

[2] These typical values are measured at V<sub>CC</sub> = 3.3 V.

10.1 Test circuits



10.2 ON resistance

Table 8. ON resistance
At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Figure 10 to Figure 15.

| Symbol    | Parameter            | Conditions                                                              | −40 °C to +85 °C |                    |     | −40 °C to +125 °C |     | Unit |
|-----------|----------------------|-------------------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|           |                      |                                                                         | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| RON(peak) | ON resistance (peak) | $V_I = GND$ to $V_{CC}$ ; see Figure 9                                  |                  |                    |     |                   |     |      |
|           |                      | $I_{SW} = 4\text{ mA}$ ;<br>$V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$ | -                | 34.0               | 130 | -                 | 195 | Ω    |
|           |                      | $I_{SW} = 8\text{ mA}$ ; $V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$      | -                | 12.0               | 30  | -                 | 45  | Ω    |
|           |                      | $I_{SW} = 12\text{ mA}$ ; $V_{CC} = 2.7\text{ V}$                       | -                | 10.4               | 25  | -                 | 38  | Ω    |
|           |                      | $I_{SW} = 24\text{ mA}$ ; $V_{CC} = 3\text{ V}$ to $3.6\text{ V}$       | -                | 7.8                | 20  | -                 | 30  | Ω    |
|           |                      | $I_{SW} = 32\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$     | -                | 6.2                | 15  | -                 | 23  | Ω    |

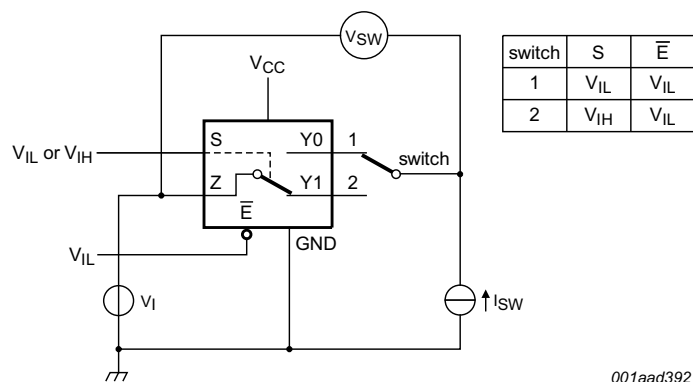


**Table 8.** ON resistance ...continuedAt recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see [Figure 10](#) to [Figure 15](#).

| Symbol                | Parameter                | Conditions                                                      | -40 °C to +85 °C |                    |     | -40 °C to +125 °C |     | Unit |
|-----------------------|--------------------------|-----------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|                       |                          |                                                                 | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| R <sub>ON(rail)</sub> | ON resistance (rail)     | V <sub>I</sub> = GND; see <a href="#">Figure 9</a>              |                  |                    |     |                   |     |      |
|                       |                          | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V   | -                | 8.2                | 18  | -                 | 27  | Ω    |
|                       |                          | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V        | -                | 7.1                | 16  | -                 | 24  | Ω    |
|                       |                          | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                | -                | 6.9                | 14  | -                 | 21  | Ω    |
|                       |                          | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3 V to 3.6 V         | -                | 6.5                | 12  | -                 | 18  | Ω    |
|                       |                          | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V       | -                | 5.8                | 10  | -                 | 15  | Ω    |
|                       |                          | V <sub>I</sub> = V <sub>CC</sub> ; see <a href="#">Figure 9</a> |                  |                    |     |                   |     |      |
|                       |                          | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V   | -                | 10.4               | 30  | -                 | 45  | Ω    |
|                       |                          | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V        | -                | 7.6                | 20  | -                 | 30  | Ω    |
|                       |                          | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                | -                | 7.0                | 18  | -                 | 27  | Ω    |
|                       |                          | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3 V to 3.6 V         | -                | 6.1                | 15  | -                 | 23  | Ω    |
|                       |                          | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V       | -                | 4.9                | 10  | -                 | 15  | Ω    |
| R <sub>ON(flat)</sub> | ON resistance (flatness) | V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[2]</sup>          |                  |                    |     |                   |     |      |
|                       |                          | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V   | -                | 26.0               | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V        | -                | 5.0                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                | -                | 3.5                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3 V to 3.6 V         | -                | 2.0                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V       | -                | 1.5                | -   | -                 | -   | Ω    |

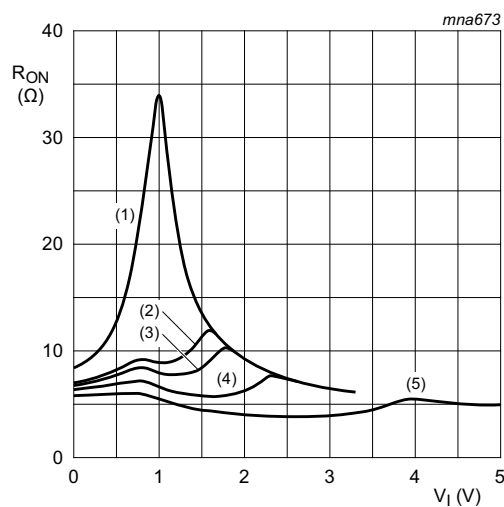
[1] Typical values are measured at T<sub>amb</sub> = 25 °C and nominal V<sub>CC</sub>.[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

### 10.3 ON resistance test circuit and graphs



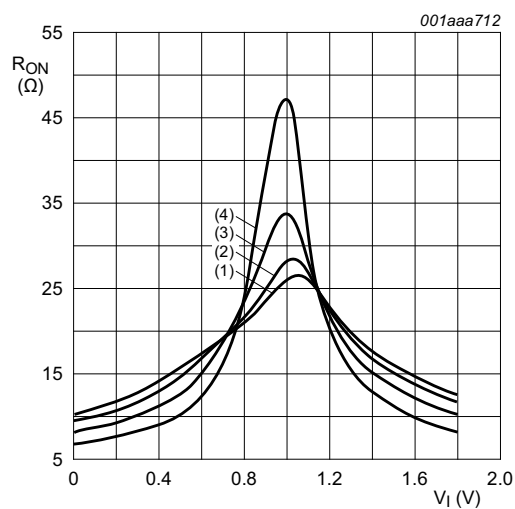
$$R_{ON} = V_{SW} / I_{SW}$$

**Fig 9.** Test circuit for measuring ON resistance



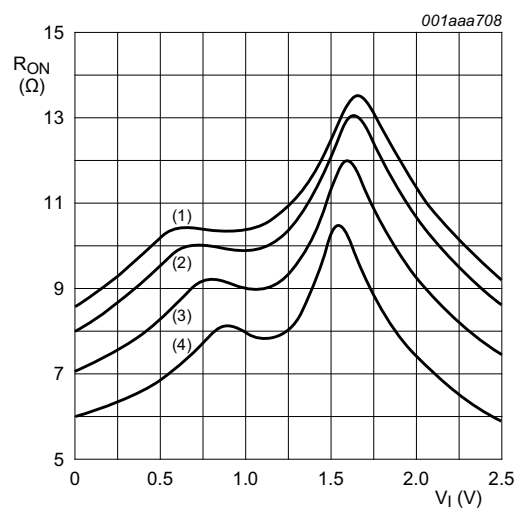
- (1)  $V_{CC} = 1.8 \text{ V}$ .
- (2)  $V_{CC} = 2.5 \text{ V}$ .
- (3)  $V_{CC} = 2.7 \text{ V}$ .
- (4)  $V_{CC} = 3.3 \text{ V}$ .
- (5)  $V_{CC} = 5.0 \text{ V}$ .

Fig 10. Typical ON resistance as a function of input voltage;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$



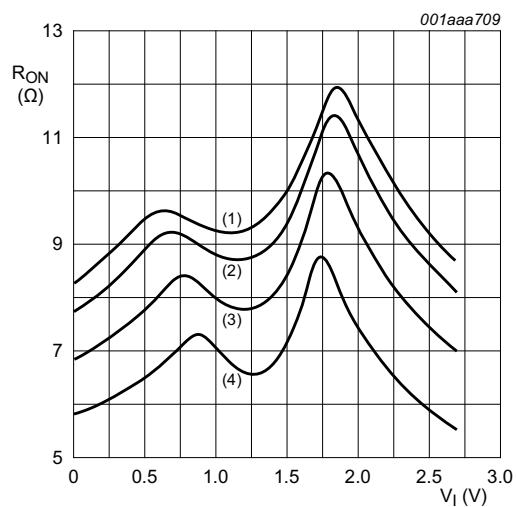
- (1)  $T_{amb} = 125 \text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85 \text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40 \text{ }^{\circ}\text{C}$ .

Fig 11. ON resistance as a function of input voltage;  
 $V_{CC} = 1.8 \text{ V}$



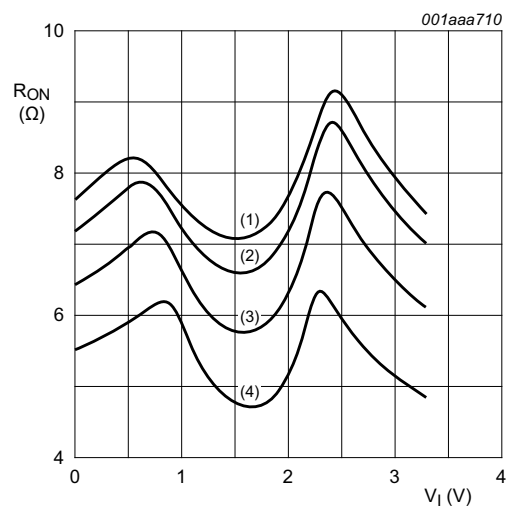
- (1)  $T_{amb} = 125 \text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85 \text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40 \text{ }^{\circ}\text{C}$ .

Fig 12. ON resistance as a function of input voltage;  
 $V_{CC} = 2.5 \text{ V}$



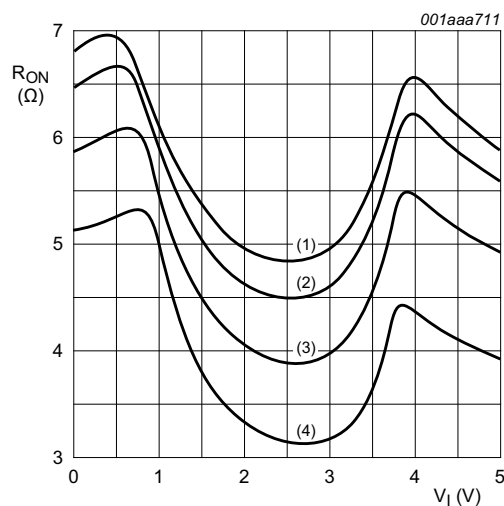
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C.}$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C.}$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C.}$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C.}$

**Fig 13. ON resistance as a function of input voltage;**  
 $V_{CC} = 2.7\text{ V}$



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C.}$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C.}$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C.}$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C.}$

**Fig 14. ON resistance as a function of input voltage;**  
 $V_{CC} = 3.3\text{ V}$



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C.}$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C.}$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C.}$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C.}$

**Fig 15. ON resistance as a function of input voltage;  $V_{CC} = 5.0\text{ V}$**

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 18](#).

| Symbol           | Parameter         | Conditions                                                                                  | –40 °C to +85 °C |                    |      | –40 °C to +125 °C |      | Unit |
|------------------|-------------------|---------------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|                  |                   |                                                                                             | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| t <sub>pd</sub>  | propagation delay | Z to Y <sub>n</sub> or Y <sub>n</sub> to Z; see <a href="#">Figure 16</a> <sup>[2][3]</sup> |                  |                    |      |                   |      |      |
|                  |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                          | -                | -                  | 2    | -                 | 2.5  | ns   |
|                  |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                            | -                | -                  | 1.2  | -                 | 1.5  | ns   |
|                  |                   | V <sub>CC</sub> = 2.7 V                                                                     | -                | -                  | 1.0  | -                 | 1.25 | ns   |
|                  |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                                                            | -                | -                  | 0.8  | -                 | 1.0  | ns   |
|                  |                   | V <sub>CC</sub> = 4.5 V to 5.5 V                                                            | -                | -                  | 0.6  | -                 | 0.8  | ns   |
| t <sub>en</sub>  | enable time       | S to Z or Y <sub>n</sub> ; see <a href="#">Figure 17</a> <sup>[4]</sup>                     |                  |                    |      |                   |      |      |
|                  |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                          | 2.6              | 6.7                | 10.3 | 2.6               | 12.9 | ns   |
|                  |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                            | 1.9              | 4.1                | 6.4  | 1.9               | 8.0  | ns   |
|                  |                   | V <sub>CC</sub> = 2.7 V                                                                     | 1.9              | 4.0                | 5.5  | 1.8               | 7.0  | ns   |
|                  |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                                                            | 1.8              | 3.4                | 5.0  | 1.8               | 6.3  | ns   |
|                  |                   | V <sub>CC</sub> = 4.5 V to 5.5 V                                                            | 1.3              | 2.6                | 3.8  | 1.3               | 4.8  | ns   |
|                  |                   | $\bar{E}$ to Z or Y <sub>n</sub> ; see <a href="#">Figure 17</a> <sup>[4]</sup>             |                  |                    |      |                   |      |      |
|                  |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                          | 1.9              | 4.0                | 7.3  | 1.9               | 9.2  | ns   |
|                  |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                            | 1.4              | 2.5                | 4.4  | 1.4               | 5.5  | ns   |
|                  |                   | V <sub>CC</sub> = 2.7 V                                                                     | 1.1              | 2.6                | 3.9  | 1.1               | 4.9  | ns   |
|                  |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                                                            | 1.2              | 2.2                | 3.8  | 1.2               | 4.8  | ns   |
|                  |                   | V <sub>CC</sub> = 4.5 V to 5.5 V                                                            | 1.0              | 1.7                | 2.6  | 1.0               | 3.3  | ns   |
| t <sub>dis</sub> | disable time      | S to Z or Y <sub>n</sub> ; see <a href="#">Figure 17</a> <sup>[5]</sup>                     |                  |                    |      |                   |      |      |
|                  |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                          | 2.1              | 6.8                | 10.0 | 2.1               | 12.5 | ns   |
|                  |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                            | 1.4              | 3.7                | 6.1  | 1.4               | 7.7  | ns   |
|                  |                   | V <sub>CC</sub> = 2.7 V                                                                     | 1.4              | 4.9                | 6.2  | 1.4               | 7.8  | ns   |
|                  |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                                                            | 1.1              | 4.0                | 5.4  | 1.1               | 6.8  | ns   |
|                  |                   | V <sub>CC</sub> = 4.5 V to 5.5 V                                                            | 1.0              | 2.9                | 3.8  | 1.0               | 4.8  | ns   |
|                  |                   | $\bar{E}$ to Z or Y <sub>n</sub> ; see <a href="#">Figure 17</a> <sup>[5]</sup>             |                  |                    |      |                   |      |      |
|                  |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                          | 2.3              | 5.6                | 8.6  | 2.3               | 11.0 | ns   |
|                  |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                            | 1.2              | 3.2                | 4.8  | 1.2               | 6.0  | ns   |
|                  |                   | V <sub>CC</sub> = 2.7 V                                                                     | 1.4              | 4.0                | 5.2  | 1.4               | 6.5  | ns   |
|                  |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                                                            | 2.0              | 3.7                | 5.0  | 2.0               | 6.3  | ns   |
|                  |                   | V <sub>CC</sub> = 4.5 V to 5.5 V                                                            | 1.3              | 2.9                | 3.8  | 1.3               | 4.8  | ns   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and nominal V<sub>CC</sub>.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

[3] Propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).

[4] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.

[5] t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>.

11.1 Waveforms and test circuits

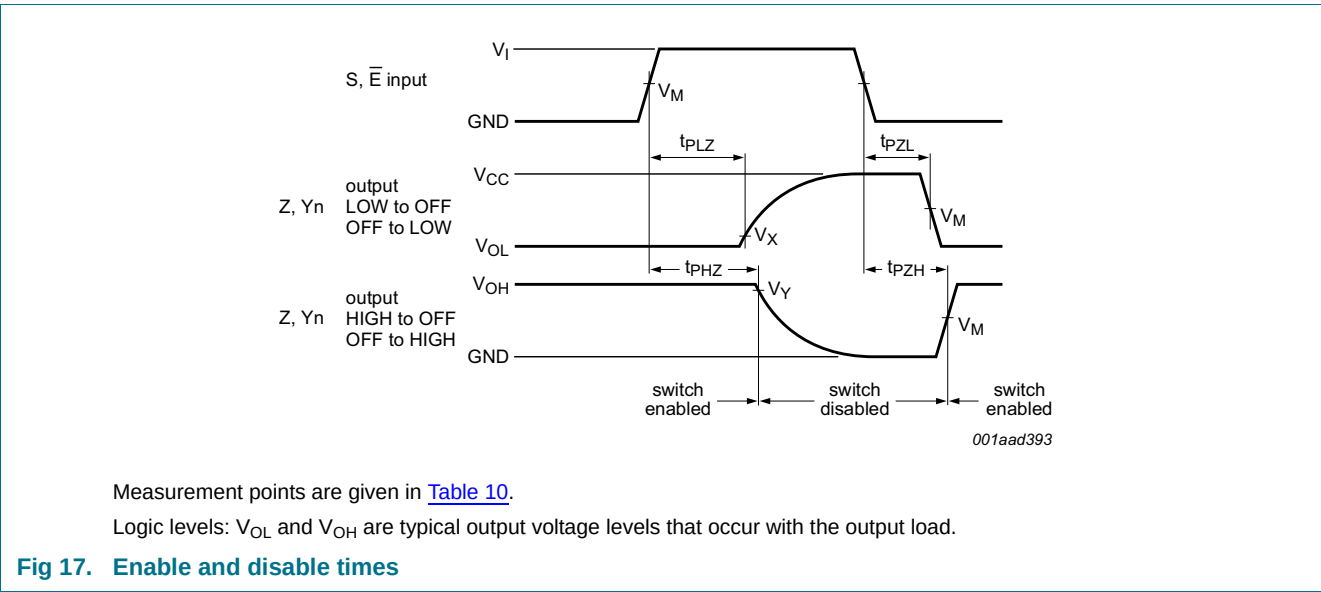
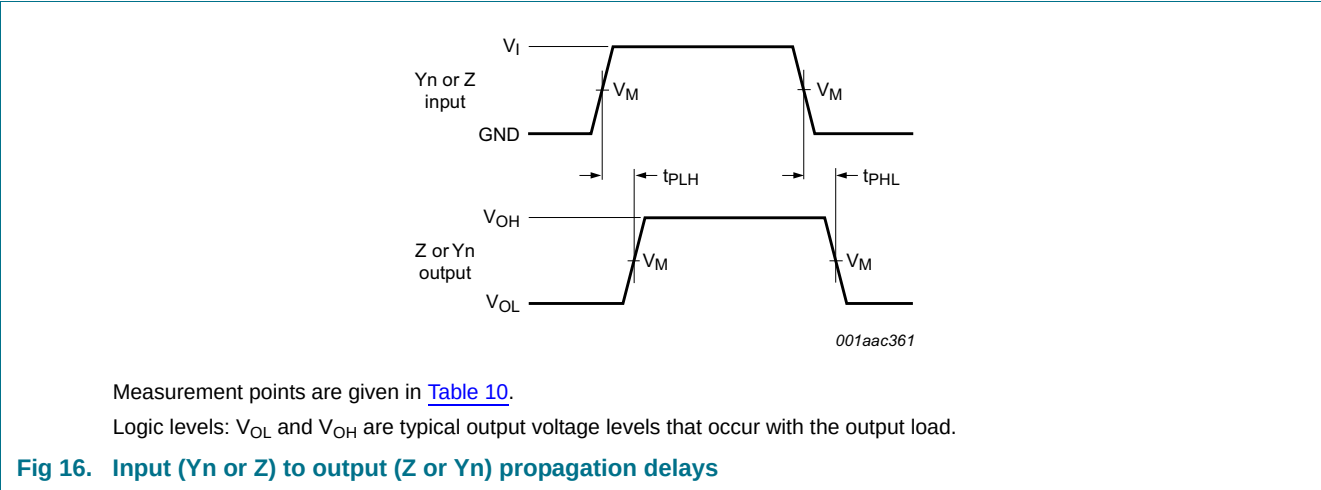
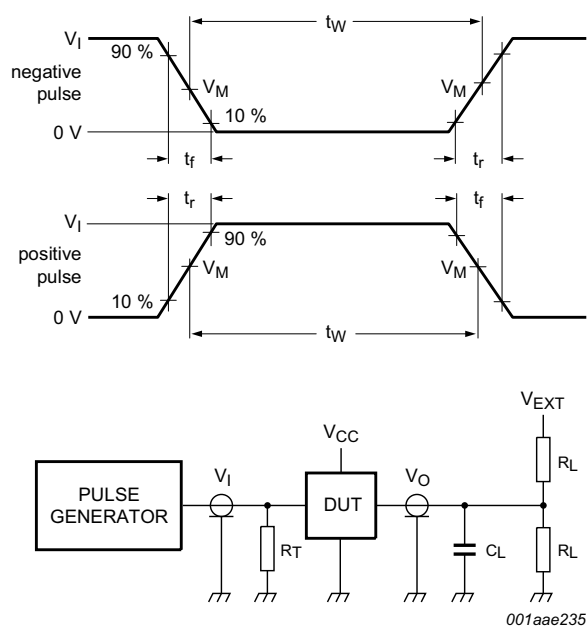


Table 10. Measurement points

| Supply voltage  | Input       | Output      |                          |                          |
|-----------------|-------------|-------------|--------------------------|--------------------------|
| $V_{CC}$        | $V_M$       | $V_M$       | $V_X$                    | $V_Y$                    |
| 1.65 V to 2.7 V | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| 2.7 V to 5.5 V  | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |



Test data is given in [Table 11](#).  
Definitions for test circuit:  
 $R_L$  = Load resistor.  
 $C_L$  = Load capacitance including jig and probe capacitance.  
 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.  
 $V_{EXT}$  = Test voltage for switching times.

Fig 18. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage   | Input    |               | Load  |              | $V_{EXT}$          |                    |                    |
|------------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| $V_{CC}$         | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 1 k $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.7 V            | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |
| 3 V to 3.6 V     | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |

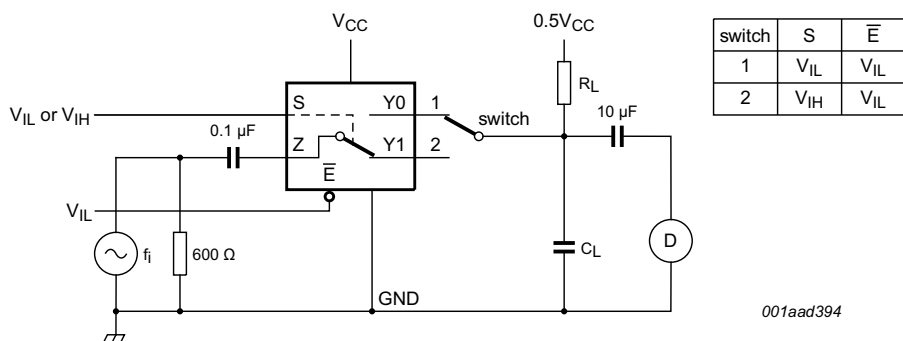
## 11.2 Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

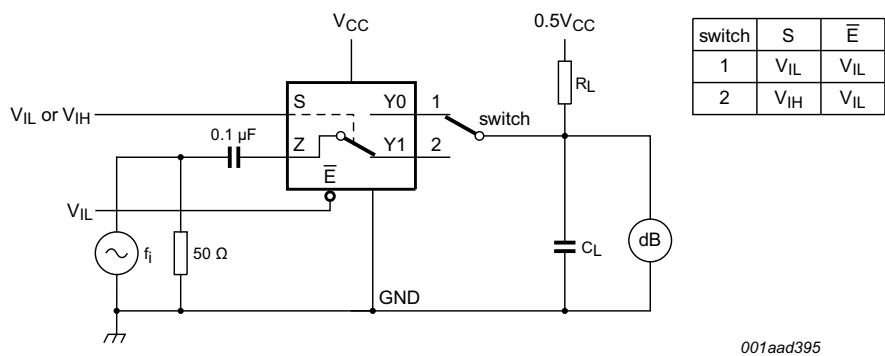
At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

| Symbol              | Parameter                 | Conditions                                                                                                                                                     | Min | Typ   | Max | Unit |
|---------------------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-------|-----|------|
| THD                 | total harmonic distortion | $f_i = 600\text{ Hz to }20\text{ kHz}$ ; $R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ; $V_I = 0.5\text{ V (p-p)}$ ; see <a href="#">Figure 19</a>         |     |       |     |      |
|                     |                           | $V_{CC} = 1.65\text{ V}$                                                                                                                                       | -   | 0.260 | -   | %    |
|                     |                           | $V_{CC} = 2.3\text{ V}$                                                                                                                                        | -   | 0.078 | -   | %    |
|                     |                           | $V_{CC} = 3.0\text{ V}$                                                                                                                                        | -   | 0.078 | -   | %    |
|                     |                           | $V_{CC} = 4.5\text{ V}$                                                                                                                                        | -   | 0.078 | -   | %    |
| $f_{(-3\text{dB})}$ | –3 dB frequency response  | $R_L = 50\text{ }\Omega$ ; $C_L = 5\text{ pF}$ ; see <a href="#">Figure 20</a>                                                                                 |     |       |     |      |
|                     |                           | $V_{CC} = 1.65\text{ V}$                                                                                                                                       | -   | 200   | -   | MHz  |
|                     |                           | $V_{CC} = 2.3\text{ V}$                                                                                                                                        | -   | 300   | -   | MHz  |
|                     |                           | $V_{CC} = 3.0\text{ V}$                                                                                                                                        | -   | 300   | -   | MHz  |
|                     |                           | $V_{CC} = 4.5\text{ V}$                                                                                                                                        | -   | 300   | -   | MHz  |
| $\alpha_{iso}$      | isolation (OFF-state)     | $R_L = 50\text{ }\Omega$ ; $C_L = 5\text{ pF}$ ; $f_i = 10\text{ MHz}$ ; see <a href="#">Figure 21</a>                                                         |     |       |     |      |
|                     |                           | $V_{CC} = 1.65\text{ V}$                                                                                                                                       | -   | –42   | -   | dB   |
|                     |                           | $V_{CC} = 2.3\text{ V}$                                                                                                                                        | -   | –42   | -   | dB   |
|                     |                           | $V_{CC} = 3.0\text{ V}$                                                                                                                                        | -   | –40   | -   | dB   |
|                     |                           | $V_{CC} = 4.5\text{ V}$                                                                                                                                        | -   | –40   | -   | dB   |
| $Q_{inj}$           | charge injection          | $C_L = 0.1\text{ nF}$ ; $V_{gen} = 0\text{ V}$ ; $R_{gen} = 0\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; $R_L = 1\text{ M}\Omega$ ; see <a href="#">Figure 22</a> |     |       |     |      |
|                     |                           | $V_{CC} = 1.8\text{ V}$                                                                                                                                        | -   | 3.3   | -   | pC   |
|                     |                           | $V_{CC} = 2.5\text{ V}$                                                                                                                                        | -   | 4.1   | -   | pC   |
|                     |                           | $V_{CC} = 3.3\text{ V}$                                                                                                                                        | -   | 5.0   | -   | pC   |
|                     |                           | $V_{CC} = 4.5\text{ V}$                                                                                                                                        | -   | 6.4   | -   | pC   |
|                     |                           | $V_{CC} = 5.5\text{ V}$                                                                                                                                        | -   | 7.5   | -   | pC   |

## 11.3 Test circuits

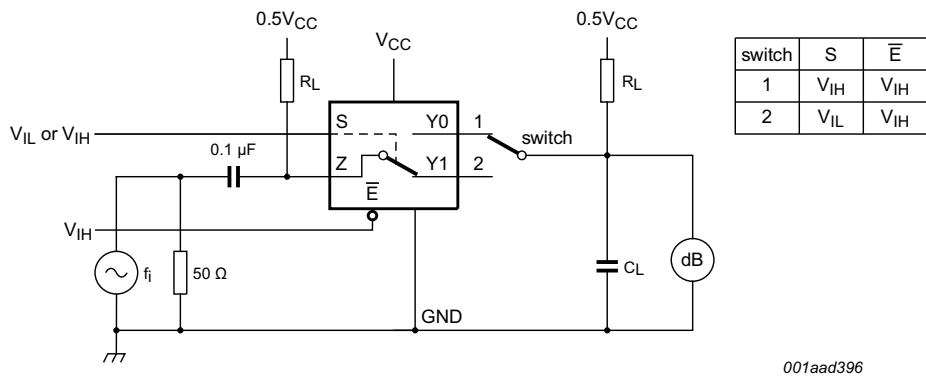


**Fig 19. Test circuit for measuring total harmonic distortion**



Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.

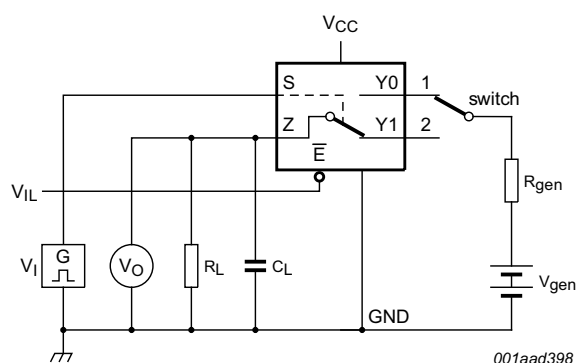
Fig 20. Test circuit for measuring the frequency response when switch is in ON-state



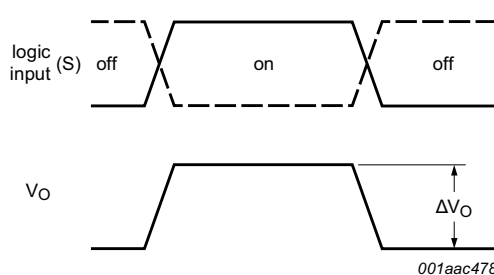
Adjust  $f_i$  voltage to obtain 0 dBm level at input.

Fig 21. Test circuit for measuring isolation (OFF-state)





a. Test circuit



b. Input and output pulse definitions

$$Q_{inj} = \Delta V_O \times C_L$$

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

$V_{gen}$  = generator voltage.

**Fig 22. Test circuit for measuring charge injection**

12. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

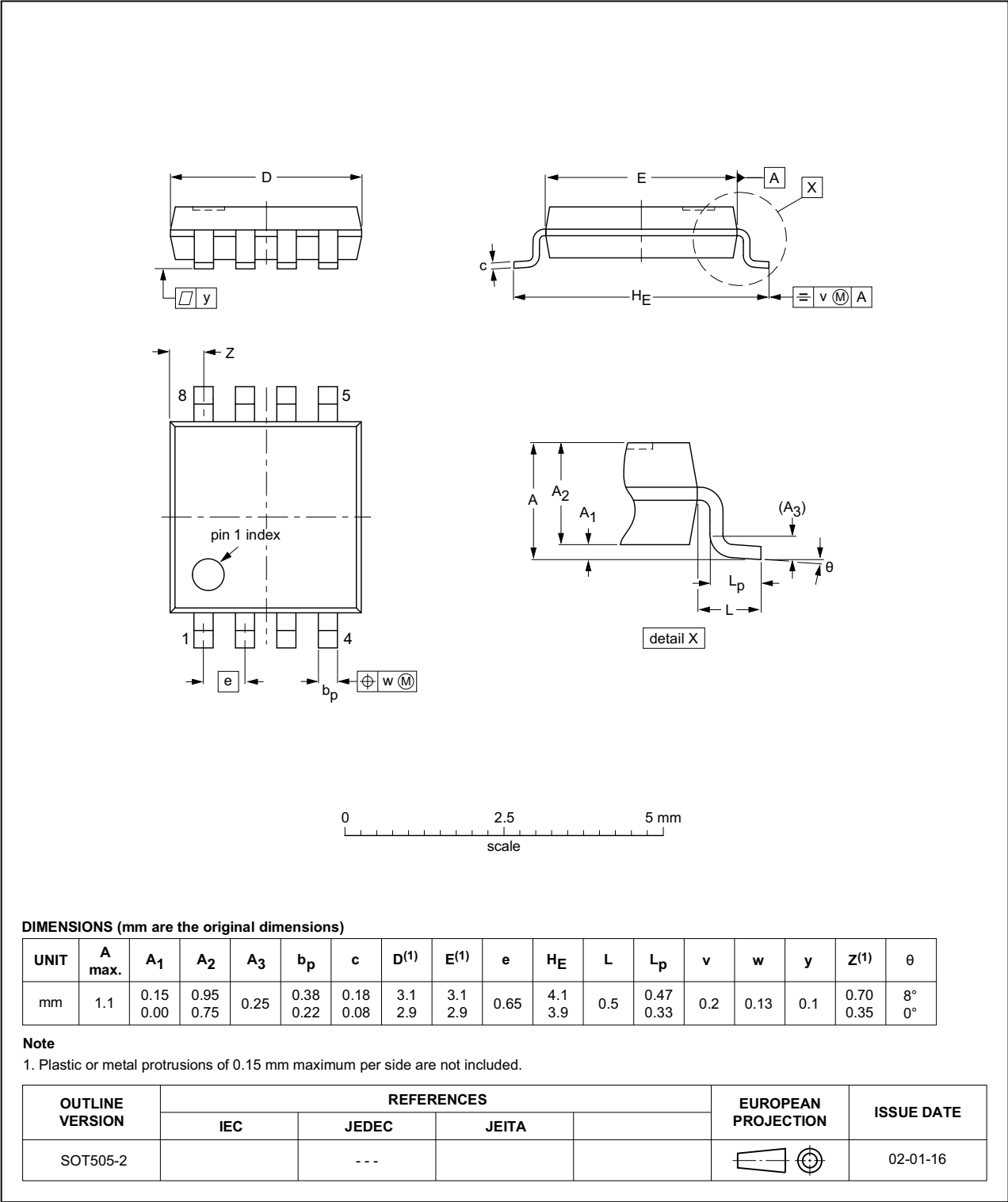


Fig 23. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

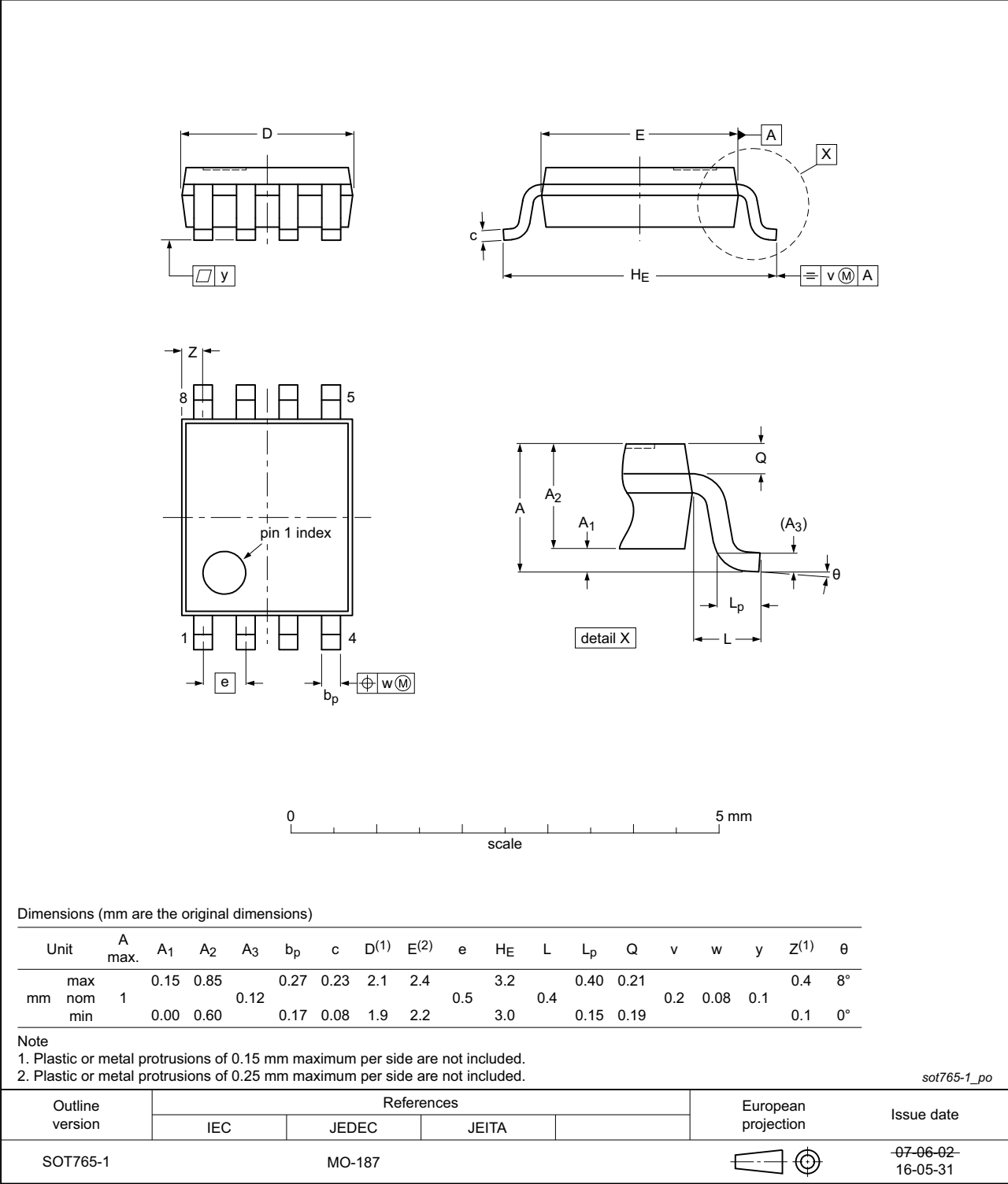


Fig 24. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

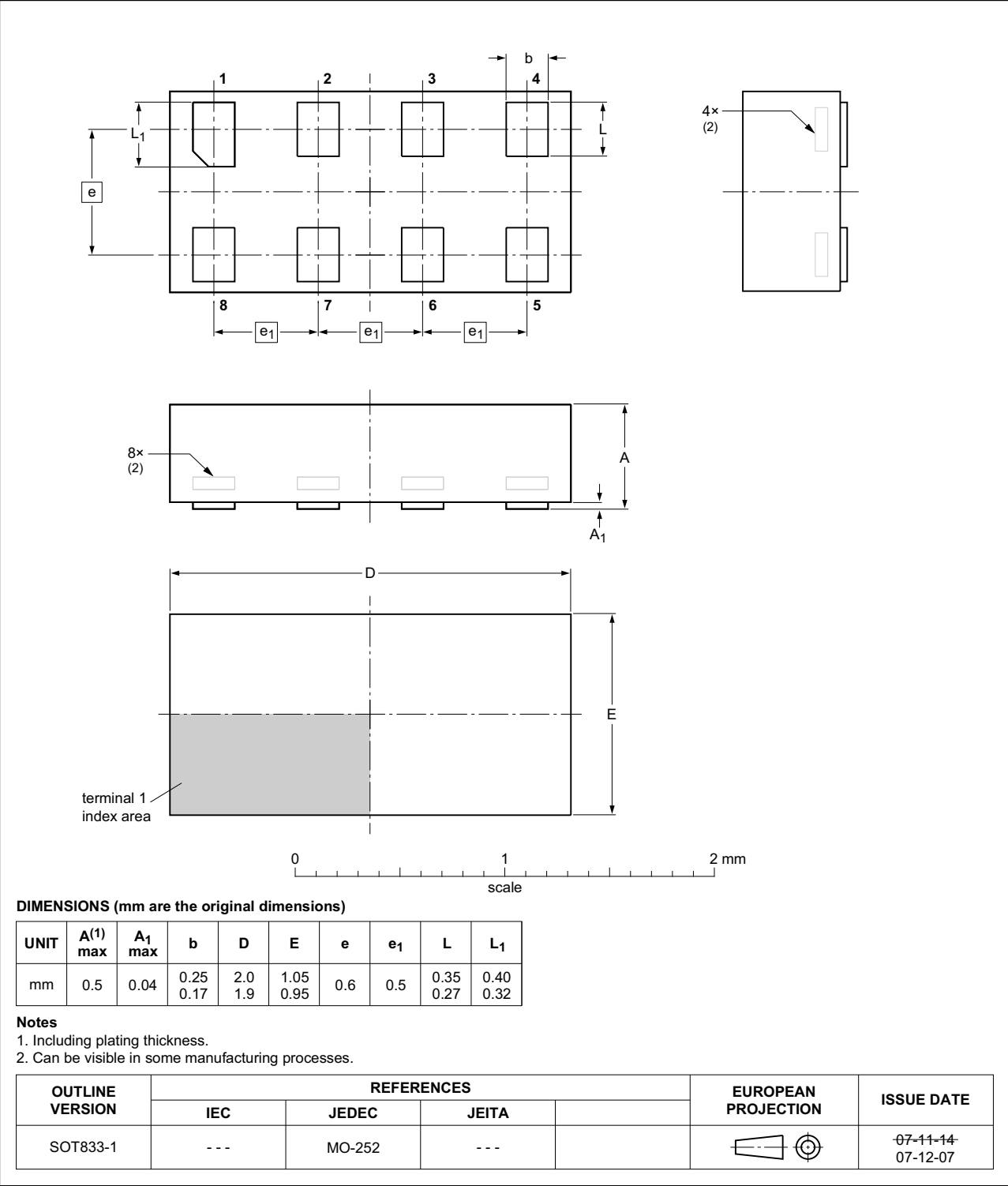


Fig 25. Package outline SOT833-1 (XSON8)

**XSON8: extremely thin small outline package; no leads;**  
**8 terminals; body 1.35 x 1 x 0.5 mm**

SOT1089

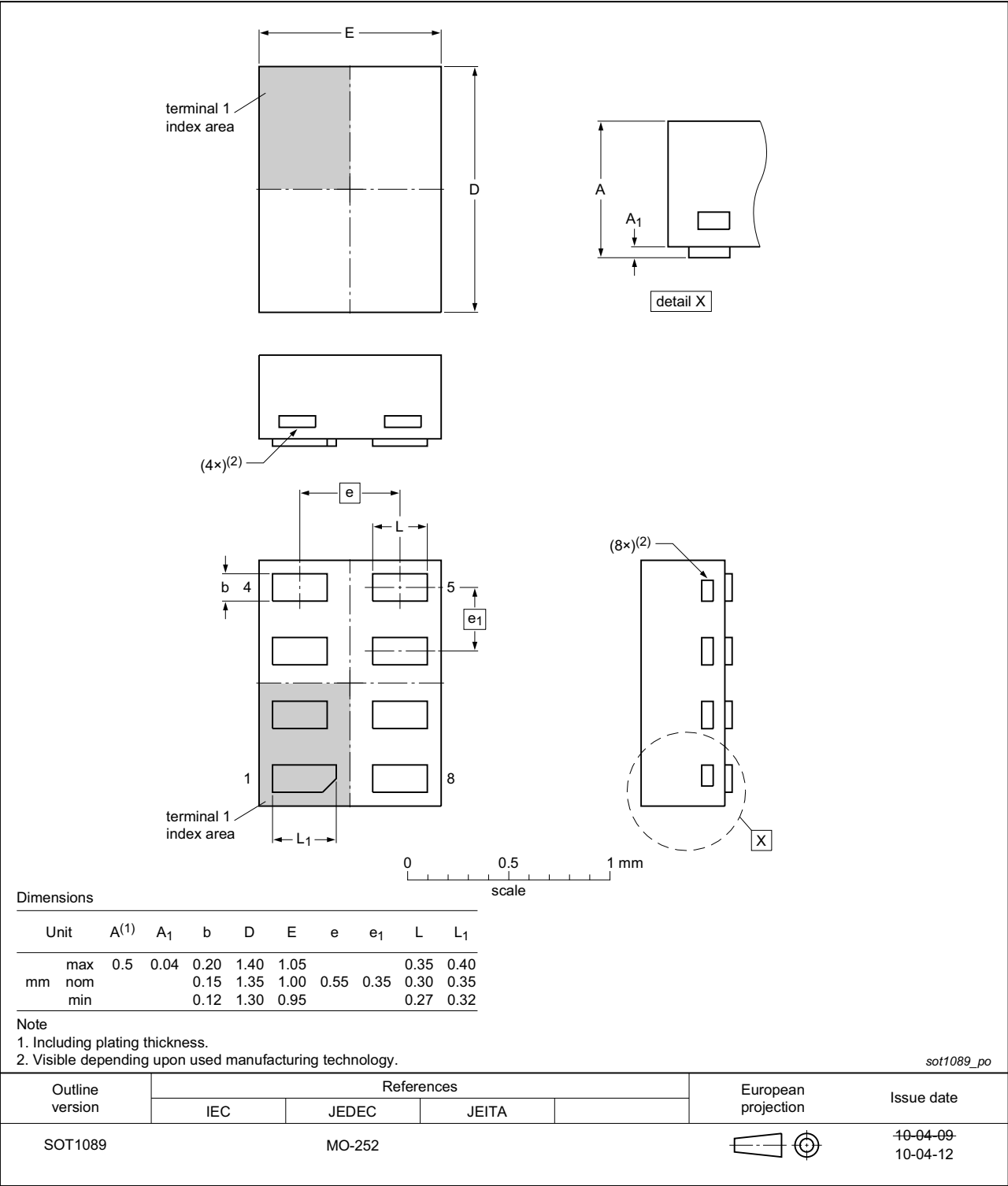


Fig 26. Package outline SOT1089 (XSON8)

XSON8: plastic extremely thin small outline package; no leads;  
8 terminals; body 3 x 2 x 0.5 mm

SOT996-2

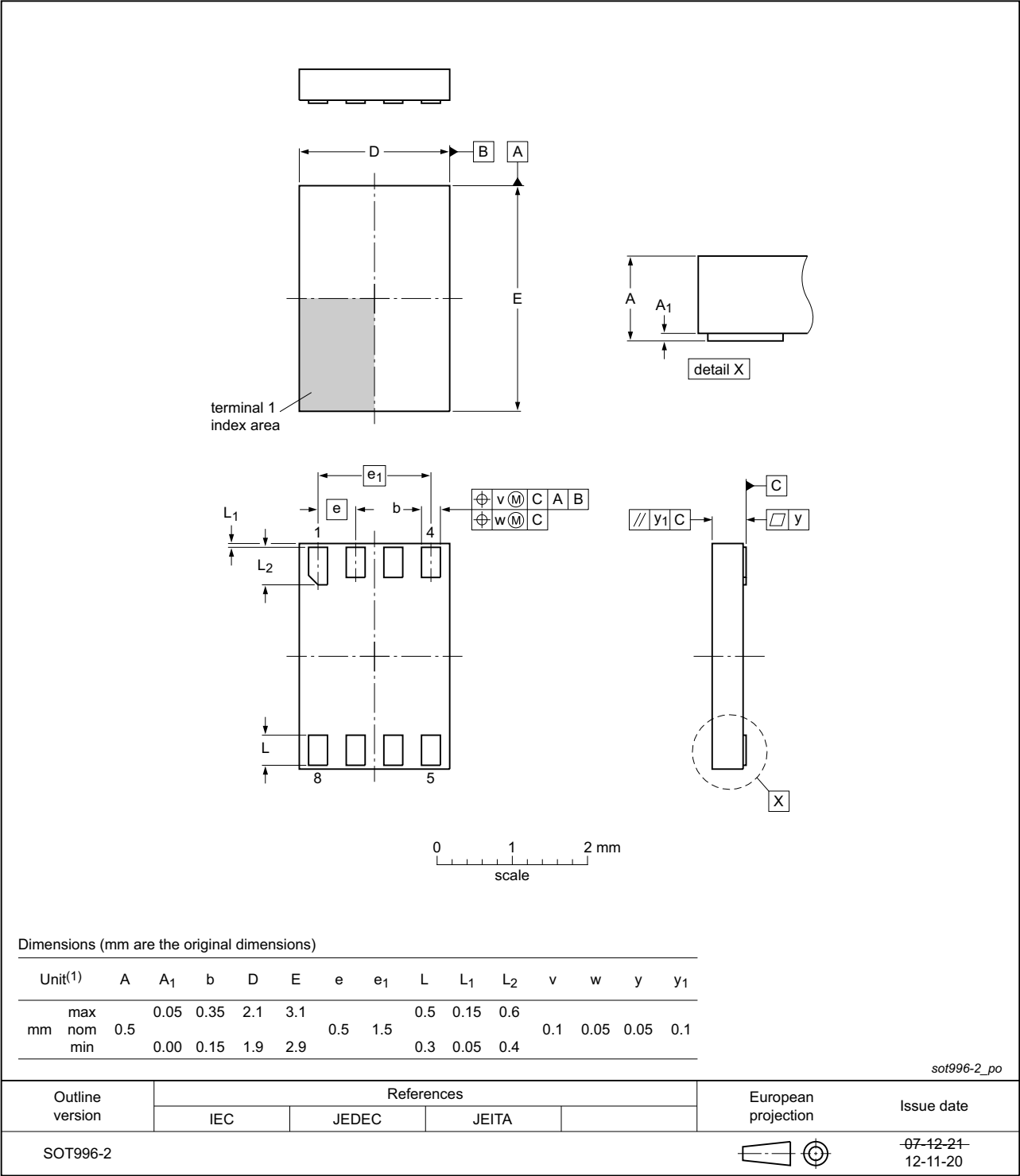


Fig 27. Package outline SOT996-2 (XSON8)

**XQFN8: plastic, extremely thin quad flat package; no leads;**  
**8 terminals; body 1.6 x 1.6 x 0.5 mm**

SOT902-2

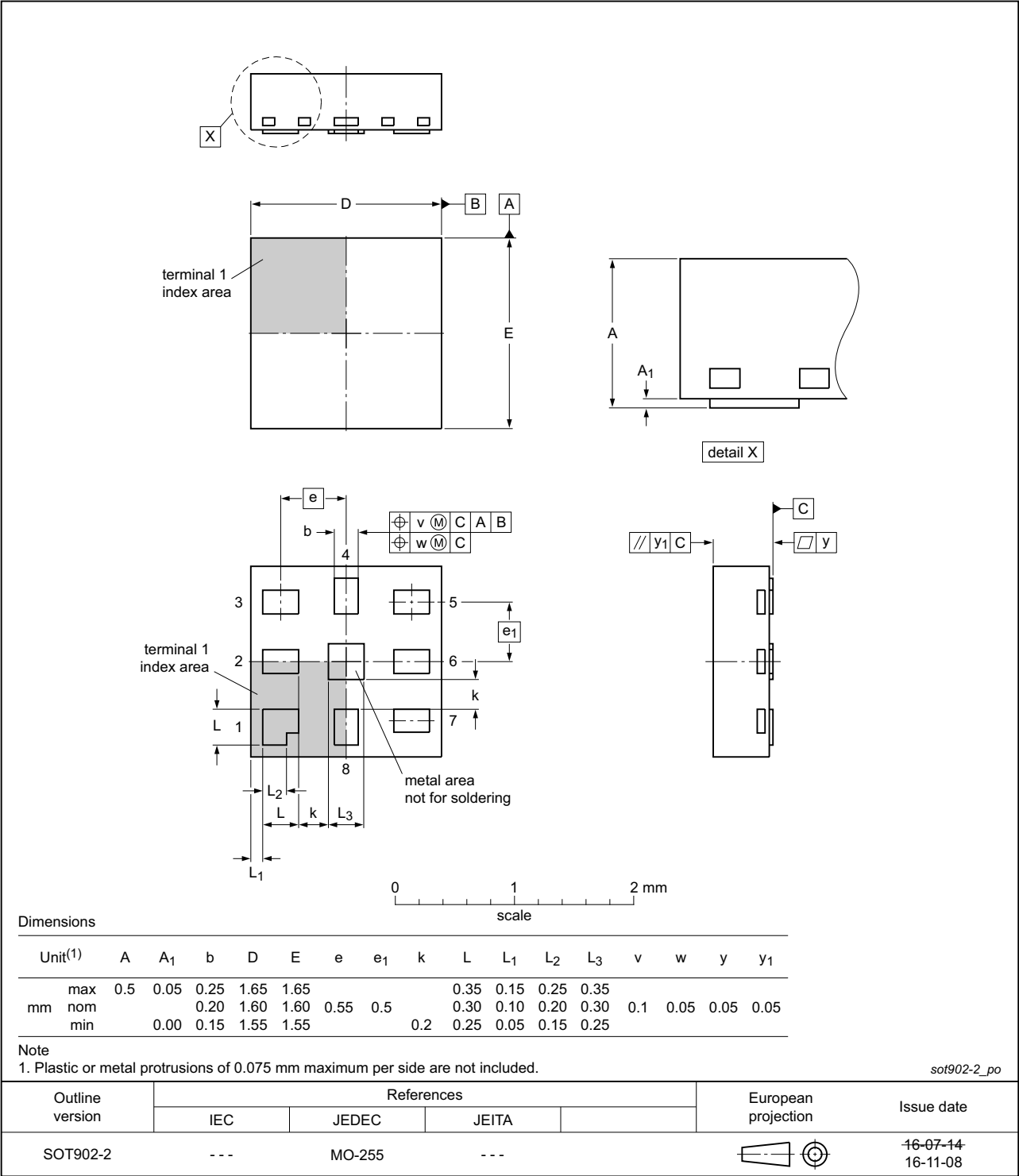


Fig 28. Package outline SOT902-2 (XQFN8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.2 x 1.0 x 0.35 mm

SOT1116

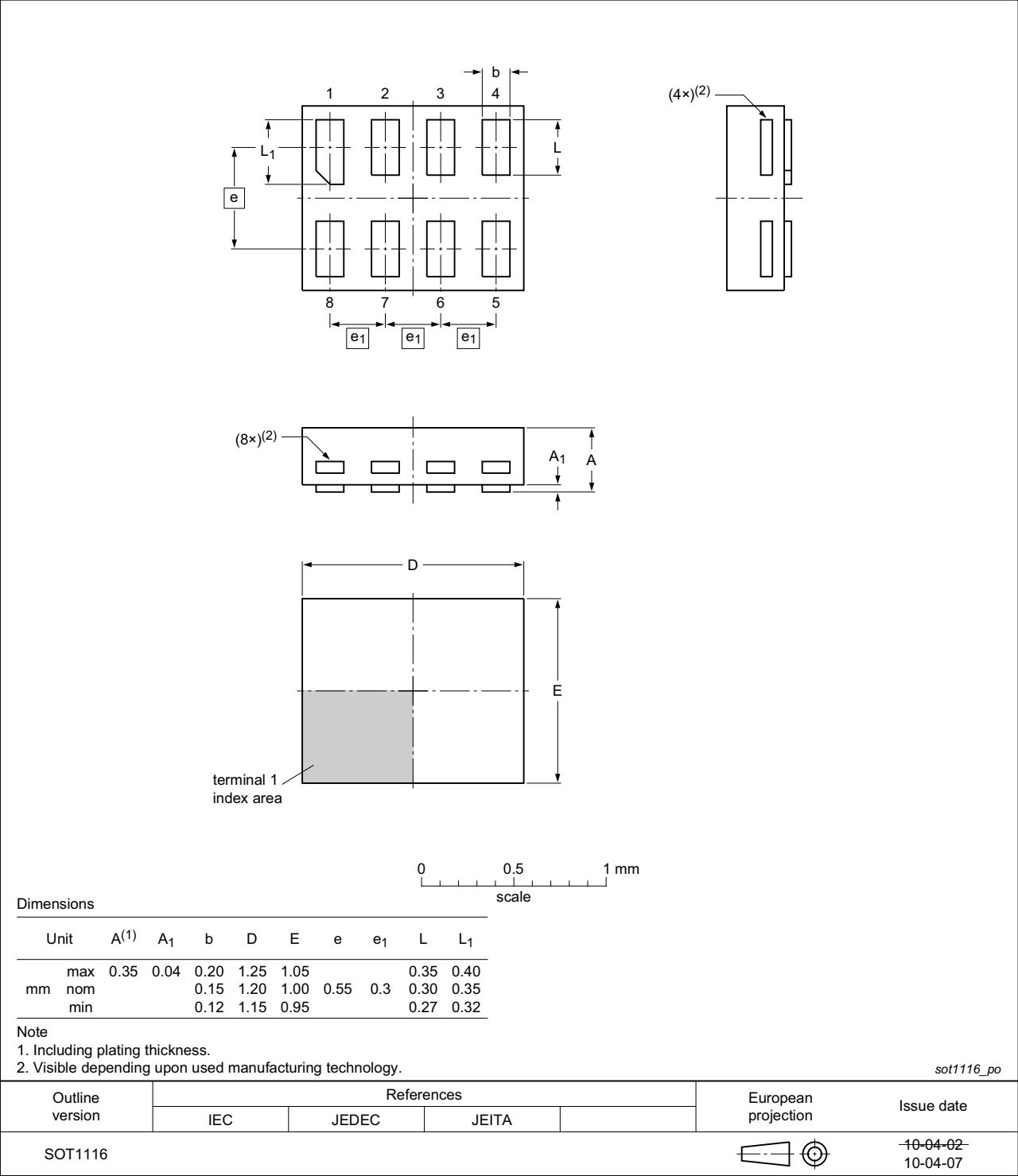


Fig 29. Package outline SOT1116 (XSON8)



**XSON8: extremely thin small outline package; no leads;**  
**8 terminals; body 1.35 x 1.0 x 0.35 mm**

SOT1203

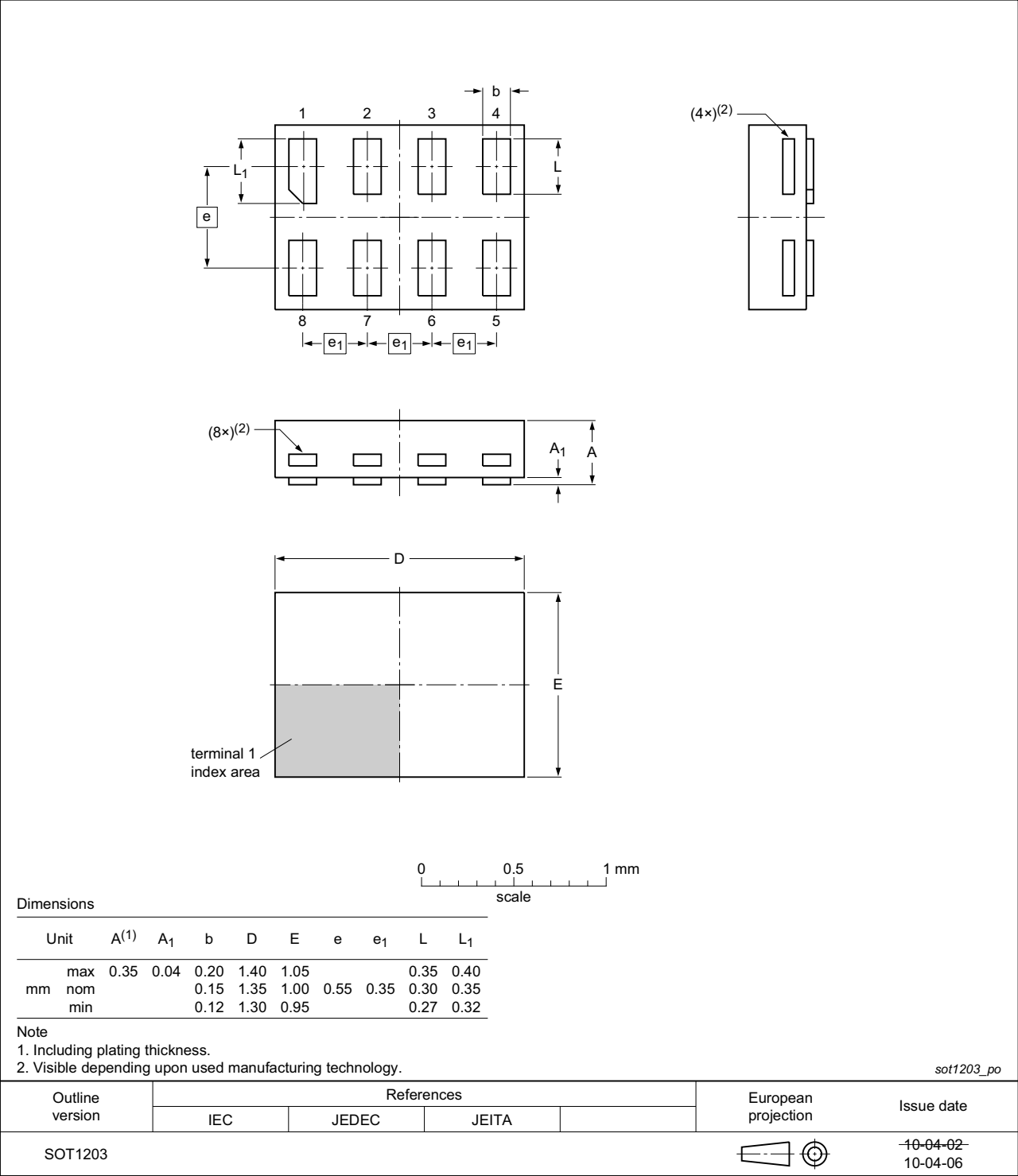


Fig 30. Package outline SOT1203 (XSON8)

## 13. Abbreviations

Table 13. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| CDM     | Charged Device Model                    |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 14. Revision history

Table 14. Revision history

| Document ID    | Release date                                                                                                                                       | Data sheet status  | Change notice | Supersedes    |
|----------------|----------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|---------------|
| 74LVC2G53 v.10 | 20161215                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.9 |
| Modifications: | <ul style="list-style-type: none"> <li><a href="#">Table 7</a>: The maximum limits for leakage current and supply current have changed.</li> </ul> |                    |               |               |
| 74LVC2G53 v.9  | 20130405                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.8 |
| Modifications: | <ul style="list-style-type: none"> <li>For type number 74LVC2G53GD XSON8U has changed to XSON8.</li> </ul>                                         |                    |               |               |
| 74LVC2G53 v.8  | 20120622                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.7 |
| Modifications: | <ul style="list-style-type: none"> <li>For type number 74LVC2G53GM the SOT code has changed to SOT902-2.</li> </ul>                                |                    |               |               |
| 74LVC2G53 v.7  | 20111125                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.6 |
| Modifications: | <ul style="list-style-type: none"> <li>Legal pages updated.</li> </ul>                                                                             |                    |               |               |
| 74LVC2G53 v.6  | 20100927                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.5 |
| 74LVC2G53 v.5  | 20080618                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.4 |
| 74LVC2G53 v.4  | 20080228                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.3 |
| 74LVC2G53 v.3  | 20070828                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.2 |
| 74LVC2G53 v.2  | 20060331                                                                                                                                           | Product data sheet | -             | 74LVC2G53 v.1 |
| 74LVC2G53 v.1  | 20060110                                                                                                                                           | Product data sheet | -             | -             |

## 15. Legal information

### 15.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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